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Optical *in situ* monitoring during the synthesis of halide perovskite solar cells reveals formation kinetics and evolution of optoelectronic properties†

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The formation mechanism and the evolution of optoelectronic properties during annealing of chlorine-derived methylammonium lead iodide (MAPbI_{3-x}Cl_x) are investigated in detail combining *in situ* and *ex situ* optical and structural characterization. Using *in situ* optical reflectometry we are able to monitor the evolution of the MAPbI_{3-x}Cl_x phase as a function of time and processing temperature. The formation kinetics is fitted using an improved Johnson–Mehl–Avrami–Kolmogorov model and a delayed formation of MAPbI_{3-x}Cl_x is found when chlorine is present in the precursor. This is verified by X-ray diffraction and X-ray fluorescence measurements. From absolute photoluminescence measurements we determine the implied V_{oc} during film formation, which exhibits a maximum at a specific time during the annealing process. In conjunction with *ex situ* time-resolved photoluminescence we deduce a decrease in the net doping density for increased annealing times, while the minority carrier lifetime stays constant. We thus demonstrate the potential of *in situ* optical spectroscopy to monitor and tailor the electronic properties of hybrid perovskites directly during film growth, which can be easily applied to different growth recipes and synthesis environments.

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1. Introduction

Metal-halide perovskite solar cells have risen to fame due to their rapid increase in power conversion efficiency to above 25%,¹ which has been achieved by systematic device, compositional^{2–4} and process engineering.^{5,6} A growing number of synthesis routes are being reported in the quest to optimize the optoelectronic properties of the perovskite absorber layer.^{7–9} Especially methylammonium lead iodide has been synthesized by many procedures that often differ in the choice of precursors,^{10–13} their ratio, and solvents utilized.^{8,14} Hence preparation protocols become increasingly complex.

A deeper understanding of how precursors, intermediates and film preparation conditions determine the optoelectronic quality of the metal halide perovskite materials is crucial to: (1)

ensure reproducibility of samples within individual laboratories (2) facilitate the adaptation of synthesis protocols and allow comparison between research laboratories and (3) translate device technology to larger areas.^{15–19} It has been found that the formation of MAPbI₃ competes with decomposition into PbI₂ such that there is only a relatively small time-window to achieve pure MAPbI₃ without precursor residues or impurity phases such as PbI₂.^{12,20} Obtaining materials with well-defined properties reproducibly is crucial to enable the technological utilization of metal-halide perovskites. Ideally, process monitoring and integrated process control would enable to adjust or terminate annealing when optimal material properties are achieved. Lab-based monitoring tools such as optical monitoring are very fast and thus may allow real-time control.²¹ Although real-time photoluminescence monitoring during perovskite growth has been reported previously^{22–24} this has so far not been performed in a realistic device fabrication environment *e.g.* in a glovebox and, even more importantly, so far neither quantitatively analyzed with respect to the evolution of structural and optoelectronic properties of the growing films.

Several studies have focused on understanding the basic mechanisms during the formation of perovskite films.^{12,25–30} Among the most investigated processes has been the formation of MAPbI_{3-x}Cl_x involving chloride-containing lead precursors such as PbCl₂. This synthesis route results in thin-films with

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long minority charge carrier diffusion lengths and photoluminescence lifetimes as well as low series resistance and good morphology, comparable to materials grown from pure iodide precursors.^{31,32} Recently, a record $V_{oc} = 1.26$ V has been demonstrated using such a synthesis route.¹³ In contrast to the PbI_2 -based route, there is no need for additional steps such as an anti-solvent drip. The unique combination of good optoelectronic properties and an easy synthesis protocol makes the process exceptionally well suited for up-scaling approaches. The role of chloride in the growth from chloride-containing precursors has been widely debated in literature. Chloride has been suggested to act as a dopant or trap state passivant to rationalize the longer charge carrier lifetimes and higher mobility.^{31,33} A photoluminescence microscopy study revealed a correlation between an enhanced Cl-content and the local photoluminescence lifetime in individual grains.³⁴ While chlorine has been confirmed to be present in the precursor phase immediately after spin coating, the chlorine content decreases during annealing by loss of methylammoniumchloride (MACl). The chloride-content in annealed films was found to be only a few percent, varying throughout the depth of the film.^{30,35–38}

The formation process itself and especially the crystalline intermediate phases containing chloride were found to be of significant importance, as they template the growth of large grain-size, oriented and high-quality material. Several studies have been carried out to elucidate the key intermediates and film formation kinetics.^{25,29,30,32,39–41} Stone *et al.* identified an intermediate phase as MA_2PbClI_3 , consisting of a columnar structure of lead-iodide-chloride octahedra.²⁸ While in previous studies mainly X-ray diffraction-based methods were applied to describe and monitor the growth process in hybrid perovskite thin films,^{12,20,28–30,40,41} there has been also a recent study in which solar cell properties were simultaneously monitored during growth, by use of a special device structure with interdigitated back contacts.⁴² Although this study gives information about the evolution of photovoltaic parameters during the growth of these specialized devices, the concept is not easily transferable to an *in situ* analysis of the optoelectronic properties of real planar devices.

In contrast, the approach followed in the present study focuses on lab-based *in situ* monitoring of UV/Vis reflectance and photoluminescence during the formation process in a real processing environment (glove box), which can be applied to any real growth process currently used for planar hybrid perovskite devices. In particular, by contact-less monitoring of the evolution of optoelectronic properties during $MAPbI_{3-x}Cl_x$ film formation we are able to identify distinctively different phases during the film formation process and deduce the kinetics of precursor phase consumption, intermediate phase formation and consumption, as well as final product formation. *Ex situ* powder X-ray diffraction (XRD) as well as X-ray fluorescence (XRF) measurements on samples after defined annealing times are used to identify intermediate phases and quantify the relative chlorine content in the sample as a function of annealing time. Here we furthermore correlate the evolution of the band-gap and photoluminescence peak emission energy with the concentration of $MAPbI_{3-x}Cl_x$ already formed, the photoluminescence quantum yield (PLQY) as well as

photoluminescence lifetime to gain insight into the charge carrier dynamics as a function of annealing time and chlorine content. In particular, the PLQY allows us to directly estimate one of the most relevant photovoltaic parameters, the device open-circuit voltage, during the growth/annealing process. This demonstrates that by *in situ* optical monitoring of the $MAPbI_{3-x}Cl_x$ formation, an optimal end-point of the annealing process can be defined for specific synthesis procedures, opening the way to further significant improvements of performance and reproducibility of halide perovskite based photovoltaics.

2. Results and discussion

2.1 Monitoring optical properties during growth

To investigate the evolution of the optoelectronic properties during the formation of the perovskite thin-film from the spin-coated precursor solution, the samples were monitored by spectrally-resolved reflectance and photoluminescence (PL) measurements in a realistic glove-box processing environment, as sketched in Fig. 1a. In Fig. 1b, heat maps of the PL and reflectance spectra for a $MAPbI_{3-x}Cl_x$ sample are shown as a function of time during the drying and subsequent annealing process at 100 °C. The synthesis process is further described in the Experimental methods section. The shift of the PL peak energy as obtained from a Gaussian-fit to the individual spectra, and the evolution of the absorption onset as obtained from spectral fitting as described below, are indicated as grey traces in the plot. Already during the drying process at $t < 0$ min the sample is strongly luminescent with an emission energy close to 1.7 eV. After ramping the temperature up to 100 °C, the luminescence peak position decreases continuously down to 1.6 eV for the fully annealed film. The emission intensity decreases within the first minutes but increases again after around 40 min. At this time the reflectance spectra also start to exhibit a clear absorption edge at 1.6 eV, which increases in energy over time. After the PL intensity goes through a maximum it decreases again after $t \sim 60$ min.

To investigate changes in the crystalline phases during the different processing stages, room temperature XRD measurements were performed on samples from process interruptions at defined annealing times of 0 min, 40 min, 45 min, 60 min and 70 min as shown in Fig. 2. Already during the drying stage ($t \leq 0$ min), when strong PL emission at 1.7 eV is observed, the XRD pattern shows diffraction peaks from a crystalline phase, in agreement with previous reports.^{25,28} The XRD pattern exhibits diffraction peaks at 11°, 12°, 15.6°, 16°, 28.5° and 32.7°, which do not agree with those expected for the binary precursor or impurity phases MAI, MACl, PbI_2 or $PbCl_2$.

The presence of crystalline precursor phases during annealing and their subsequent decomposition, simultaneously to the formation of $MAPbI_3$ has been discussed for different precursor salts.^{20,25,27,39} In the case of the $PbCl_2$ -derived synthesis route, diffraction peaks comparable with lattice distances in crystalline $MAPbCl_3$ (ref. 25) have led to the conclusion that a pure or chloride-rich methylammonium lead halide perovskite could be a component of the crystalline



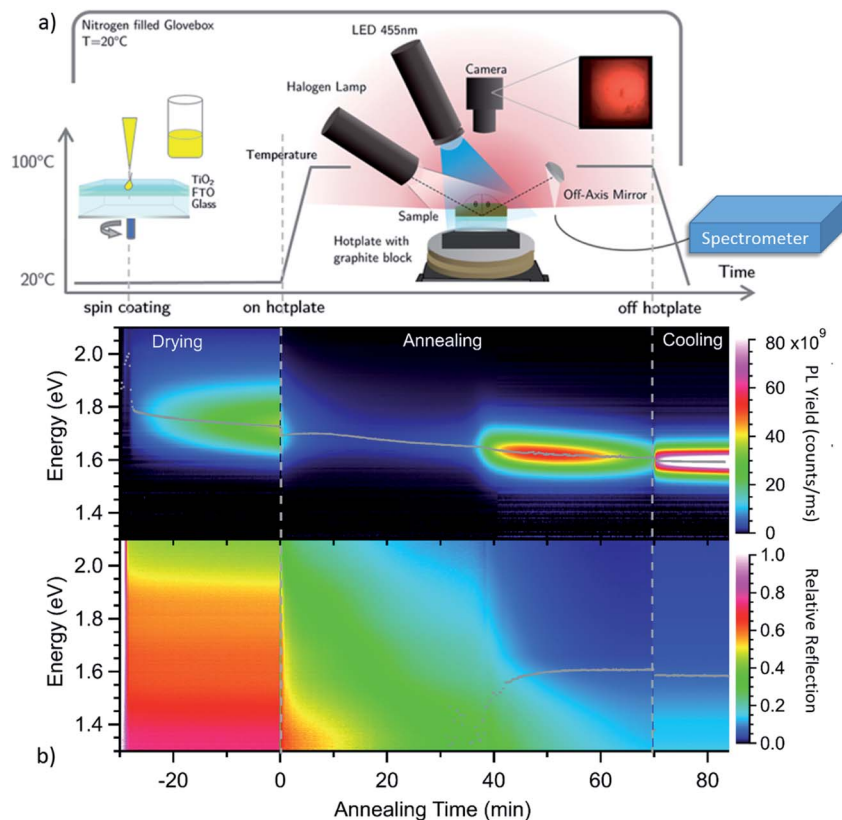


Fig. 1 (a) Schematic of the glovebox-based synthesis and optical monitoring process. A camera image of the photoluminescence emitted from the sample after 60 min annealing shown in red colors is shown as an inset. (b) False-color plot of the evolution of photoluminescence (PL) and reflection spectra during the 3-stage synthesis of chlorine derived $\text{MAPbI}_{3-x}\text{Cl}_x$. The PL peak energy as well as the energy of the band gap, as obtained from fitting the individual spectra, are superimposed.

precursor phase.^{25,32,43–45} The associated lattice plane distances of the diffraction peaks at 15.6° and 32.7° are indeed consistent with those of MAPbCl_3 . However, some of the diffraction peaks expected for MAPbCl_3 , such as the (011) and (022) peaks, are not observed in the powder diffractogram of our samples (see Fig. S1 and S2 in the ESI†). Instead, all diffraction peaks are consistent with a crystalline phase of MA_2PbCl_3 (ref. 28) which

exhibits a similar near-range order but a lower local symmetry than MAPbCl_3 . In this proposed structure, chloride ions preferentially occupy the axial lattice sites of lead-iodide-chloride octahedra. Therefore, in the [002]-direction, the lattice constant is identical to that of MAPbCl_3 , resulting in the diffraction peak at 15.6° , which has sometimes been attributed to crystalline MAPbCl_3 .^{40,45}

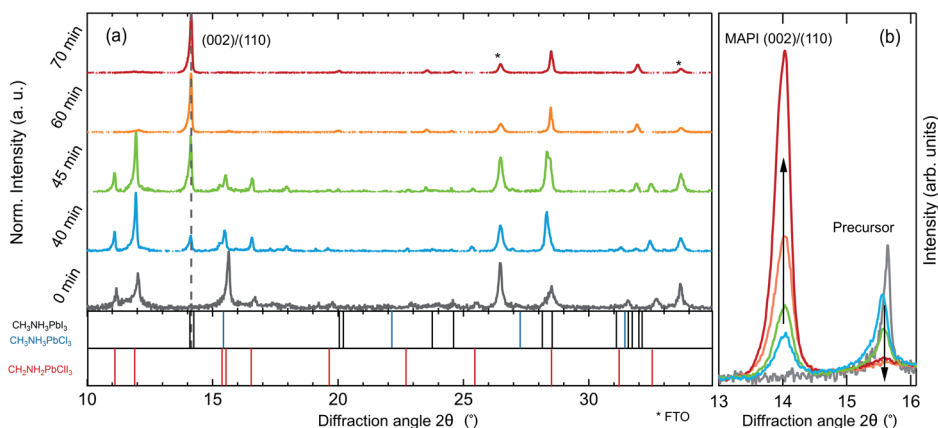


Fig. 2 (a) Normalized X-ray diffraction pattern of a $\text{MAPbI}_{3-x}\text{Cl}_x$ thin-film sample after the drying stage (0 min) as well as after respective times of annealing. The asterisks indicate the diffraction peaks from the FTO/ TiO_2 substrate. (b) Comparison of the evolution of the $\text{MAPbI}_{3-x}\text{Cl}_x$ (002)/(110) peak and the precursor peak at 15.6° .



During annealing, weak diffraction peaks evolve, that can be assigned to the tetragonal phase of $\text{MAPbI}_{3-x}\text{Cl}_x$, while the diffraction peaks of the precursor phase(s) diminish in intensity accordingly. The final film only exhibits peaks corresponding to a pure $\text{MAPbI}_{3-x}\text{Cl}_x$ phase. A direct comparison of the evolution of the peak at 15.6° attributed to the $\text{MA}_2\text{PbClI}_3$ (310)/(001) precursor and the $\text{MAPbI}_{3-x}\text{Cl}_x$ (002)/(110) peaks is shown in Fig. 2b. It is noteworthy, that the decrease of the $\text{MA}_2\text{PbClI}_3$ peak occurs in parallel to the evolution of the $\text{MAPbI}_{3-x}\text{Cl}_x$ peak but at no point in time a solid-solution of both phases exists. It can thus be concluded that the final film is not formed by ion-exchange from $\text{MA}_2\text{PbClI}_3$ but nucleates and grows while consuming the precursor phase.

Photoluminescence and optical reflection signals extracted from the *in situ* data sets at corresponding annealing times are shown in Fig. 3. The volume fraction of $\text{MAPbI}_{3-x}\text{Cl}_x$ formed in the film can be estimated from the optical reflection data by employing a Beer-Lambert law based model,²¹ assuming that light is fully reflected at the silver back mirror and thus transmitted twice through the investigated layer of thickness d :

$$R(\lambda, t) = R_0(t) + R_1(t)\exp[-\alpha(\lambda, t)2dc(t)] \quad (1)$$

where $\alpha(\lambda, t)$ is the absorption coefficient of the layer and $c(t)$ corresponds to the volume fraction of the detected phase in the film, R_0 is the reflection from the surface and R_1 is a constant. The absorption coefficient is modeled as $\alpha_0(E - E_g)^{0.5}$ for photon energies above the band gap E_g and as an exponential Urbach tail $\exp((E - E_g)/E_u)$ for energies below the band gap, corresponding to a direct-gap semiconductor with exponential sub gap band tailing.⁴⁶ More details about the fitting model can be found in the ESI (Note 2).[†]

No clear absorption edge can be discerned during the initial annealing stage between $t = 0$ min and $t = 35$ min. However, the luminescence spectrum of the dried film at $t = 0$ min, in Fig. 3a, exhibits a peak with a maximum around 1.73 eV and a significantly broadened high energy side.

At about $t = 40$ min an absorption edge can be recognized in Fig. 3b and the photoluminescence peak redshifts to about 1.6 eV, which agrees with literature values for band-to-band emission of $\text{MAPbI}_{3-x}\text{Cl}_x$ at 100°C .⁴⁷ This is supported by the XRD patterns in Fig. 2a which show an increase of the diffraction peaks corresponding to $\text{MAPbI}_{3-x}\text{Cl}_x$ between 40 min and 70 min. Thus, we propose that the variable $c(t)$ obtained from fitting the reflection data can be associated with an increasing $\text{MAPbI}_{3-x}\text{Cl}_x$ volume fraction in the film. Fig. 3 also shows the fits of the reflection spectra indicating that the spectra are well described by the model for annealing times > 35 min. Assuming that at $t = 70$ min the concentration $c = 100\%$ for the fully formed perovskite film with a film thickness of $d = 300$ nm (compare Fig. S3[†]), an absorption constant $\alpha_0 = 1.6 \times 10^5 \text{ cm}^{-1} \text{ eV}^{-0.5}$ is derived, which corresponds to an absorption coefficient of $\alpha = 2.5 \times 10^4 \text{ cm}^{-1}$ at 1.6 eV. This value is in good agreement with literature values for PbCl_2 -derived $\text{MAPbI}_{3-x}\text{Cl}_x$.⁴⁸

In Fig. 4 the PL intensity, the PL peak position, the derived $\text{MAPbI}_{3-x}\text{Cl}_x$ concentration $c(t)$ and the total chlorine content of the film (from XRF) are shown as a function of annealing time. Note that for all *ex situ* measurements the errors of the individual measurements are very low, whereas a larger uncertainty arises from the sample to sample variation. A comparison of the *ex situ* measurements and *in situ* reproducibility for different synthesis runs can be found in the ESI, Fig. S7–S9.[†] It can be seen in Fig. 4a that although a significant PL yield is present during the whole process, there is a marked increase in PL yield after 40 min followed by a decrease which, will be further analyzed in the following. Correspondingly, the $\text{MAPbI}_{3-x}\text{Cl}_x$ concentration $c(t)$ obtained from optical reflection measurements (Fig. 4b) shows a sudden increase, agreeing with the increase of the $\text{MAPbI}_{3-x}\text{Cl}_x$ phase determined from XRD measurements. Thus, the increase in PL yield can be explained by the formation of $\text{MAPbI}_{3-x}\text{Cl}_x$. The formation of $\text{MAPbI}_{3-x}\text{Cl}_x$ does not occur continuously from the beginning of the annealing but only initiates after a certain delay time. This indicates that the formation does not follow a simple first order reaction but is related to a more complex transformation mechanism, as will be discussed further in Section 2.3.

From the evolution of the chlorine content determined from XRF measurements (Fig. 4d), it is noted that the onset of the

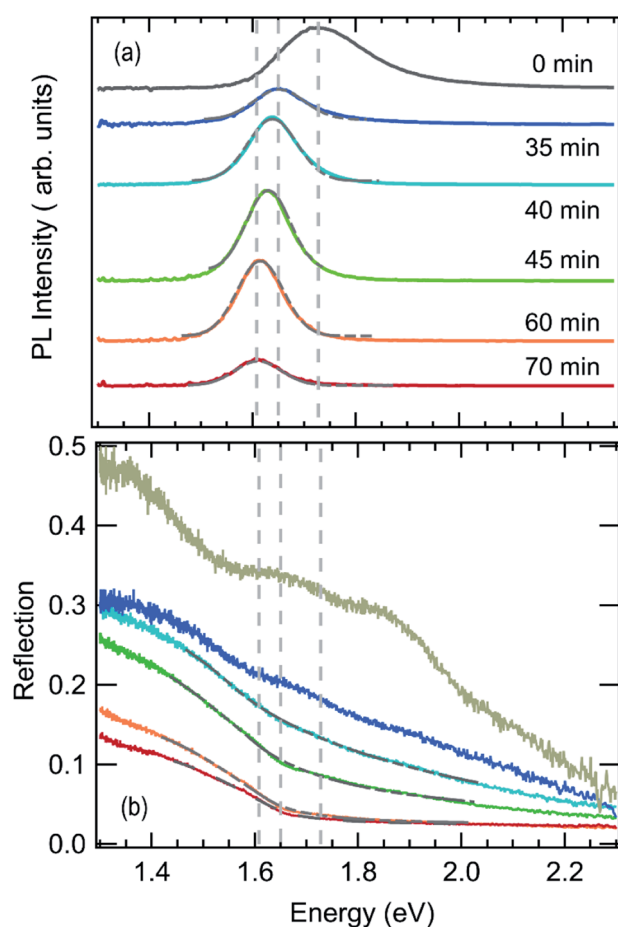


Fig. 3 Photoluminescence (a) and white light reflection (b) taken after the drying of the sample at room temperature (grey) and during subsequent annealing at 100°C . A shift in the photoluminescence peak position as well as the development of an absorption edge are visible. Grey solid lines indicate numerical fits to the data.



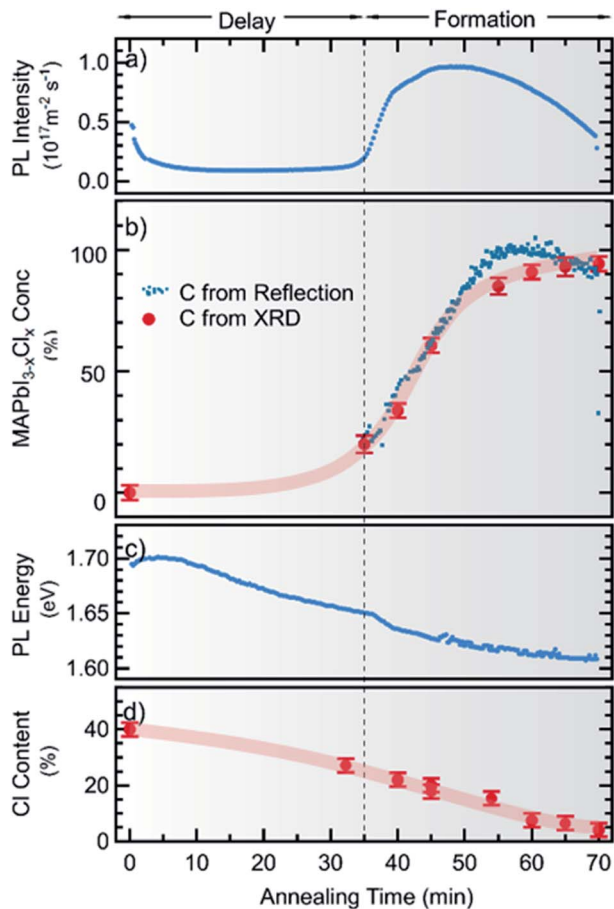


Fig. 4 Time evolution of film properties during the annealing stage of the chlorine-derived synthesis of $\text{MAPbI}_{3-x}\text{Cl}_x$ measured by *in situ* photoluminescence and reflection spectroscopy as well as *ex situ* X-ray diffraction and X-ray fluorescence spectroscopy. The obtained photoluminescence intensity is shown in the top panel (a). It can be compared to the concentration of $\text{MAPbI}_{3-x}\text{Cl}_x$ within the thin film, extracted by fitting the absorption edge of the individual reflection spectra, and the relative reflex height of $\text{MAPbI}_{3-x}\text{Cl}_x$ measured by X-ray diffraction (b). Furthermore, the PL peak energy (c) is compared to the decrease of the overall chlorine content within the sample, obtained from X-ray fluorescence (d).

$\text{MAPbI}_{3-x}\text{Cl}_x$ formation coincides with a loss of about 50% of the initial chlorine content. This observation is consistent with previous studies, which showed that chlorine is released during formation of $\text{MAPbI}_{3-x}\text{Cl}_x$ from mixed halide precursors.^{25,28} Our results indicate that no apparent transformation to $\text{MAPbI}_{3-x}\text{Cl}_x$ occurs before an apparent “excess” of Cl has evaporated during the initial annealing phase. Please note that we did not observe this delay of MAPbI_3 formation in a Cl-free processing route using only iodine-containing precursors (see Fig. S10 in the ESI†). This implies that the delay is caused by the presence of (excess) chlorine in the sample.

The PL peak position also shows an interesting behavior: at $t = 0$ min the maximum is at $E_{\text{pl}} \sim 1.7$ eV and thus cannot be attributed to pure MAPbI_3 , which has a bandgap of 1.6 eV at $T = 100$ °C.⁴⁷ During the annealing, a red shift can be observed and the PL evolves continuously into the emission consistent

with a pure MAPbI_3 phase (or $\text{MAPbI}_{3-x}\text{Cl}_x$ with small x). This continuous redshift is visible during the entire annealing time. This suggests a continuous evolution of the material luminescent at 1.7 eV at $t = 0$ into the final $\text{MAPbI}_{3-x}\text{Cl}_x$ phase. In contrast, in XRD the diffraction peaks corresponding to the $\text{MAPbI}_{3-x}\text{Cl}_x$ phase do not evolve by a continuous peak shift from the observed crystalline precursor phase. The observed luminescent precursor phase must thus be different from the crystalline precursor phase visible in XRD, but possibly arises from $\text{MAPbI}_{3-x}\text{Cl}_x$ crystallites already present at the beginning of the annealing process, as will be discussed further in Section 2.3.

2.2 Evolution of optoelectronic properties during growth

After about 45 min a decrease in photoluminescence intensity is observed, although the concentration of $\text{MAPbI}_{3-x}\text{Cl}_x$ is still rising. This clearly indicates a change in the optoelectronic properties of the material. From the photoluminescence signal and the absorbed incident photon flux the photoluminescence quantum yield (PLQY) can be calculated, which is shown in

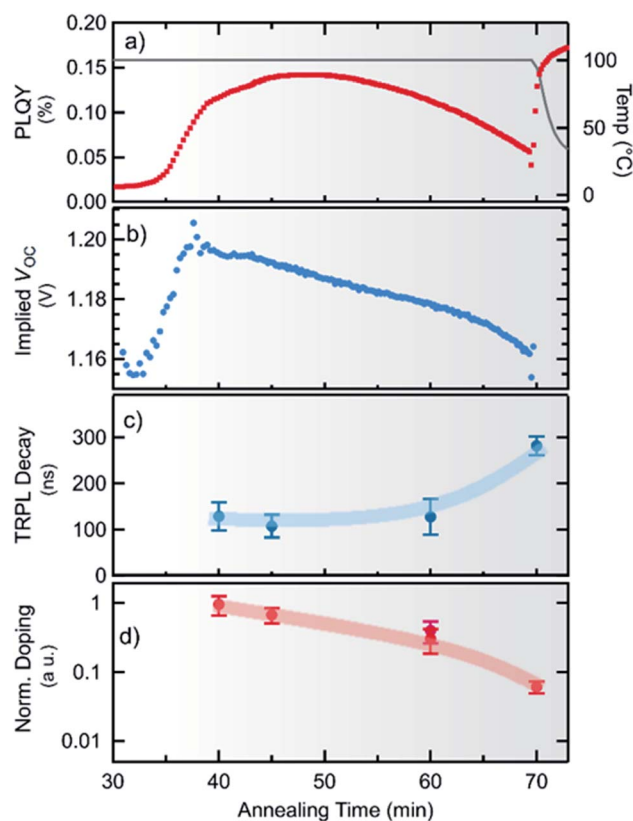


Fig. 5 Time evolution of optical properties during the annealing stage of the chlorine-derived synthesis of $\text{MAPbI}_{3-x}\text{Cl}_x$ obtained from *in situ* photoluminescence spectroscopy as well as *ex situ* time-resolved photoluminescence. In (a) and (b), the quantum yield and the implied open circuit voltage (iV_{oc}) during the process are compared. Additionally, the process temperature is shown in grey. In (c) the effective carrier lifetime as measured by TRPL is shown. (d) The normalized doping density estimated from PLQY and TRPL decay time decreases during annealing.



Fig. 5a. It can be seen, that the PLQY first reaches a maximum of 0.14% at about 48 min, and then decreases with further annealing. We note that this value compares well to recent results obtained for perovskite absorber layers yielding more than 20% conversion efficiency in devices,⁴⁹ in particular when taking into account that the processing (and thus measurement) temperature of 100 °C attenuates the PLQY by approximately a factor of 3 (see ESI, Fig. S11†).

From the temperature-corrected PLQY, the quasi-Fermi level splitting μ (or implied open-circuit voltage iV_{oc}) expected at room temperature can be estimated following the approach of Ross⁵⁰

$$\mu = \mu_{rad} + k_B T \ln(PLQY/a_e) = qiV_{oc} \quad (2)$$

where μ_{rad} denotes the quasi-Fermi level splitting in the radiative limit, which in the simplest approximation is equivalent to the Shockley–Queisser limit (~ 1.31 eV for a bandgap of 1.6 eV)⁵¹ and a_e is the absorptivity of the perovskite at the emission wavelength and $T = 300$ K (see ESI, Fig. S12†). The implied room-temperature open-circuit voltage for the growing film is shown in Fig. 5b, where it can be seen that iV_{oc} reaches a maximum value of 1.2 V after an annealing time of 38 min, and then monotonically decreases to a final value of 1.16 V at the end of the annealing process. This clearly shows that such an *in situ* monitoring approach can be applied to optimize the annealing conditions for various perovskite crystallization processes.

To estimate the minority carrier lifetime and possible changes in the charge carrier (doping) density n_0 during annealing, time-resolved photoluminescence (TRPL) measurements were performed *ex situ* after different annealing times. To account for the concentration of $MAPbI_{3-x}Cl_x$ formed after different times, the initial TRPL amplitude was corrected by the absorption of the incident laser beam. Measured TRPL transients are shown in the ESI in Fig. S13.† We find that the minority carrier lifetime stays nearly constant at $\tau \sim 130$ ns and even increases with longer times of annealing as seen in Fig. 5c. The externally observed photoluminescence yield is proportional to the radiative recombination coefficient k_{rad} , the photoexcited carrier density and the absorptivity at the emission wavelength $Y_{PL} \propto k_{rad} n p a_e$, which for low injection conditions can be approximated by $Y_{PL} \propto \tau n_0 a_e$, where τ is the minority carrier lifetime and n_0 is the net doping density.^{52–54} Although, without exact knowledge of additional constants, this does not allow the deduction of an absolute doping density, the relative change in doping density can be estimated from the PL-yield and carrier lifetime as shown in Fig. 5d. It can be seen that the doping density continuously decreases with processing time by about one order of magnitude. Thus, it can also be concluded that the observed decrease in the implied V_{oc} for longer annealing time is related to a decrease in the doping density rather than to an increase in non-radiative recombination.

A comparison with the pure PbI_2 derived synthesis route (ESI, Fig. S10†) shows that after the formation onset the photoluminescence yield shows a very similar behavior for both cases. Thus, it can be assumed that the decrease in doping

density is not primarily caused by the decrease in the chlorine content. However, for both routes a ratio of 3 : 1 of MAI/ PbI_2 or MAI/ $PbCl_2$ was used. Thus $MAPbI_3/MAPbI_{3-x}Cl_x$ is grown from an initial excess of methylammonium in both cases. In the case of $MAPbI_3$, this has been shown to result in highly p-doped $MAPbI_3$ (ref. 55) which is primarily attributed to Pb-vacancies exhibiting a rather low formation enthalpy.⁵⁶ Furthermore, it has been reported that annealing of pristine $MAPbI_3$ reduces the hole density even leading to a conversion to n-type doping.⁵⁵ Hence, the herein observed decrease in the effective doping density during the formation of $MAPbI_{3-x}Cl_x$ can be assumed to be caused by a decrease of Pb-vacancies caused by the evaporation of MA during annealing.

2.3 Formation kinetics of $MAPbI_{3-x}Cl_x$

To further analyze the reaction kinetics of the chlorine-derived $MAPbI_{3-x}Cl_x$ formation, the annealing process was carried out at different annealing temperatures (80 °C, 85 °C, 90 °C, 95 °C and 100 °C). The time evolution of the $MAPbI_{3-x}Cl_x$ concentration as derived from the reflection measurements is shown in Fig. 6. It can be seen, that the duration for a complete transformation of the film into $MAPbI_{3-x}Cl_x$ ranges from approximately 35 min at 100 °C to 180 min at 80 °C. The delay in the formation reaction of $MAPbI_{3-x}Cl_x$ ranges from approximately 15 min at 100 °C to about 80 min at 80 °C.

Kinetic parameters of the $MAPbI_{3-x}Cl_x$ formation reaction can be extracted by applying an appropriate temperature-dependent formation model for the time evolution of the $MAPbI_{3-x}Cl_x$ concentration $c(t)$. The sigmoidal kinetics observed in Fig. 6a are characteristic for solid-state transformations and can be attributed to a nucleation and growth process. The widely used Johnson–Mehl–Avrami–Kolmogorov (JMAK) model^{57–59} describes such solid-state transformation reactions at constant temperature T and has been recently applied to the formation of perovskites from precursors.¹² Model assumptions are that nucleation occurs homogeneously distributed within the precursor phase, that the growth rate is constant in time and that growth occurs homogeneously in all directions.⁵⁸ We apply the JMAK-model using a thermally activated rate equation that includes a delay time t_{onset} to account for the observed delay in $MAPbI_{3-x}Cl_x$ formation:

$$c(t) = 1 - e^{-\left(k_0 e^{-E_a^F/RT} (t - t_{onset})\right)^n}, \quad \text{for } t > t_{onset} \quad (3)$$

where E_a^F denotes the activation energy of the reaction, k_0 is the rate constant, and n is the growth dimensionality.

The dataset shown in Fig. 6a is fitted for all temperatures simultaneously, varying k_0 , E_a^F and n globally for all processes. Alternatively, t_{onset} is fixed to zero for the pure JMAK model while it assumes temperature-dependent finite values for the altered model given by eqn (3). From fitting the data in Fig. 6, it can be seen, that if the delay time is omitted ($t_{onset} = 0$ min) the global fit insufficiently describes the measured data and results in a growth dimensionality of $n = 5.5$, which is physically difficult to rationalize. When introducing a delay time $t_{onset}(T)$, the experimental data can be fitted with higher accuracy for all temperatures, which can be also seen from the χ^2 -coefficient



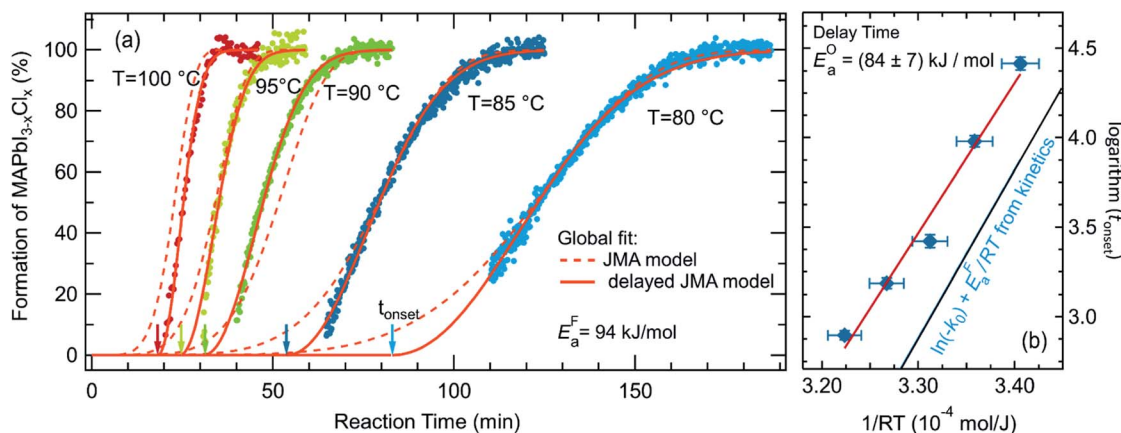


Fig. 6 Kinetic data for the samples annealed at 80 °C, 85 °C, 90 °C, 95 °C and 100 °C. (a) showing the concentration of $\text{MAPbI}_{3-x}\text{Cl}_x$ during formation together with the JMAK model fits with an assumed delay (solid lines) and without a delay (broken lines) (eqn (3)). (b) Arrhenius plot of the delay time t_{onset} as determined by the global fit to the JMAK model to extract the activation energy of the delay process, resulting in $E_a^{\text{O}} = 84 \pm 7 \text{ kJ mol}^{-1}$. As a comparison $\ln(k_0^{\text{F}}) + E_a^{\text{F}}/RT$ as obtained from the global fit of the formation kinetics for $t > t_{\text{onset}}$ is shown in blue.

which decreases from 11 to 6. The resulting activation energy of the formation reaction is $E_a^{\text{F}} = (94 \pm 2) \text{ kJ mol}^{-1}$ and the growth exponent is $n = 2.1 \pm 0.1$. The growth exponent corresponds to the dimensionality of the growth, where $n = 2$ implies 2-dimensional growth of previously nucleated material. As a growth exponent $n > 4$ bears no physical meaning, this shows that the formation of $\text{MAPbI}_{3-x}\text{Cl}_x$ can only be correctly described by including a temporal delay in the onset of $\text{MAPbI}_{3-x}\text{Cl}_x$ formation (eqn (3)).

In addition, a second activation energy can be extracted from the delay times. Fig. 6b shows an Arrhenius plot of the delay times t_{onset} yielding an activation energy of $E_a^{\text{O}} = (84 \pm 7) \text{ kJ mol}^{-1}$. Although both activation energies, estimated from the temperature dependence of $t_{\text{onset}}(T)$ and from the temperature dependence of the subsequent formation kinetics, are very close to each other we believe that they may correspond to two distinct phenomena, as discussed further below.^{12,60}

A comparison of the reaction kinetics determined in the present study with previously reported reaction kinetics observed by *in situ* GIWAXS shows some agreement and some differences (Fig. S14 in ESI†). While Chang,⁴⁰ Unger²⁵ and Stone²⁸ observe a delay, this is not observed by Moore *et al.*¹² The reported duration for complete conversion of the precursor to the final film varies from 30 min to 70 min at 100 °C and the reported activation energies vary from 69 kJ mol^{-160} to $86 \pm 6 \text{ kJ mol}^{-1}$.¹² It has to be noted, that these activation energies were obtained without including a formation delay. A comparison of the previously presented data shows that even though the formation onset differs significantly in different studies, the reaction kinetics after the formation onset obtained in the present study agree with the data presented by Chang, Unger and Stone^{25,28,40} and hence seem to be more fundamental than the delay time (see Fig. S14†). Thus, we propose that variations observed for the formation onset strongly depend on the processing conditions. The annealing environment, N_2 or dry air, varying relative humidity or ambient temperature is often not specified in detail but may have a crucial influence. This

variance in process conditions and kinetics serves as a strong argument for the relevance of *in situ* process control during growth.

The strong variation of t_{onset} visible in the literature data and in this study for different glovebox temperatures (see ESI, Fig. S7b†), together with the largely unaffected subsequent formation kinetics, indicate that the processes occurring during the delay and the formation phase itself may be distinctively different.

Considering all data from PL, UV-Vis, XRD and XRF we conclude, that MACl and MA_2PbCl_3 as well as $\text{MAPbI}_{3-x}\text{Cl}_x$ - nuclei coexist within the film from the beginning. The fact that the $\text{MAPbI}_{3-x}\text{Cl}_x$ cannot be observed by XRD in the beginning of the growth process can be explained by an initially small-domain size of the crystallites. We recall from Fig. 1 and 4 that a photoluminescence signal is observed from $t = 0$ min which starts at a peak energy of 1.7 eV and then continuously red-shifts to 1.6 eV. Although such a continuous red shift may be explained by a growth of the $\text{MAPbI}_{3-x}\text{Cl}_x$ nuclei and thus decreasing of quantum confinement, it may also be due to a continuous substitution of chlorine with iodine within the $\text{MAPbI}_{3-x}\text{Cl}_x$ seed crystals. Assuming a linear dependence of the band-gap of $\text{MAPbI}_{3-x}\text{Cl}_x$ on the chlorine content x , the PL peak energy would indicate a Cl-concentration of 6% of the original seed crystals at $t = 0$ min, subsequently reducing to about 0.6% for the fully annealed $\text{MAPbI}_{3-x}\text{Cl}_x$ film. This explanation is consistent with the Rietveld refinement of the powder diffractograms which show an increase of the unit cell volume approaching MAPbI_3 literature values for $t > 40$ min (see Fig. S2 in the ESI†), indicating a decrease of the Cl content in $\text{MAPbI}_{3-x}\text{Cl}_x$ from that point onwards.^{43,61,62}

MACl was shown to evaporate during the process²⁵ which correlates to a loss of chlorine within the film, as measured with XRF (Fig. 4). Once MACl is fully evaporated, further evaporation of chlorine leads to a decomposition of the MA_2PbCl_3 precursor. By this, the limiting elements (Pb/I) become available and thus a sudden formation onset of $\text{MAPbI}_{3-x}\text{Cl}_x$ can be



observed. Thus, we propose an activation energy of $E_a^O = (84 \pm 7)$ kJ mol⁻¹ for the loss of Cl in form of MA₂Cl during the latent phase and an activation energy $E_a^F = (94 \pm 2)$ kJ mol⁻¹ for the subsequent formation of MAPbI_{3-x}Cl_x and decomposition of MA₂PbCl₃.

3. Conclusions

The evolution of halide perovskite formation was monitored *in situ* by optical spectroscopy during a regular solar cell synthesis process in a glovebox environment. The band-edge of the growing perovskite material was observed by white light reflection and fitted with an analytical model to extract the evolution of the MAPbI₃ concentration in the thin film during annealing. Simultaneously, the optical properties of the film are monitored by photoluminescence which allows us to quantitatively deduce the implied V_{oc} during film growth.

Analyzing the MAI/PbCl₂ based synthesis route it was found that a crystalline precursor phase develops which can be attributed to MA₂PbCl₃. Furthermore, the excess of chlorine is shown to delay the onset of MAPbI_{3-x}Cl_x formation. We propose that already from the beginning of the growth process MAPbI_{3-x}Cl_x nuclei exist, (with strong luminescence at 1.7 eV) from which the MAPbI_{3-x}Cl_x layer forms only after a delay time t_{onset} . This is supported by a growth exponent of $n = 2$ for the formation of MAPbI_{3-x}Cl_x, indicating 2D growth with previous nucleation, and a PL emission which continuously approaches the final MAPbI_{3-x}Cl_x emission. By correlation with TRPL measurements we observed that the excited charge carrier lifetime stays nearly constant during annealing, however the effective doping density decreases significantly. This can be attributed to a loss of methylammoniumchloride during annealing. Thus, it is shown that through *in situ* monitoring the doping density could be fine-tuned by altering the annealing time. This work demonstrates the great potential of *in situ* optical spectroscopy in order to monitor and tailor the optoelectronic properties of hybrid perovskites directly during device processing. Furthermore, the possibility to analyze real growth processes in detail opens the way to an improved understanding and enhanced reproducibility of halide perovskite solution processing, which is a necessary prerequisite for up scaling approaches.

4. Experimental section

4.1 Perovskite synthesis

FTO coated glass substrates (Pilkington TEC7) were cleaned in an ultrasonic bath, using a laboratory cleaning agent (diluted Extran 1 : 1 with H₂O) and subsequently rinsed with distilled water and dried with N₂. The substrates were coated with a 75 nm thick layer of TiO₂ by electron beam evaporation and annealed in ambient air at 500 °C for 2 h. To enable the reflection/transmission measurements the back side of the substrates was coated with 150 nm of silver by electron beam evaporation. Methylammonium iodide (MAI) was prepared from methylamine and HI as described elsewhere.¹⁰

Lead(II) chloride was used as purchased from Sigma Aldrich. MAI and lead chloride were dissolved in anhydrous *N,N*-dimethylformamide (DMF) in a 3 : 1 ratio¹⁰ and stirred for 30 min at 20 °C in a nitrogen-filled glovebox. 150 μl of the solution were drop cast onto the TiO₂ coated substrate and spin coated at 2000 rpm for 45 s. After spin coating, the samples were first left to dry for 30 min at 20 °C (ref. 63) and afterwards annealed on a hotplate at 100 °C until the perovskite was fully formed.¹⁰

4.2 *In situ* monitoring

For the *in situ* photoluminescence a custom setup was used in which the samples are excited with a blue LED (455 nm) at an intensity of 3 mW cm⁻² and the luminescence is detected with a fiber-coupled spectrometer with a spectral range of 341 to 1022 nm and spectral resolution of 0.28 nm. *In situ* reflectance measurements were performed in the same setup using a 20 W tungsten halogen lamp for excitation and the same fiber-coupled spectrometer for signal detection.

During all room temperature measurements the temperature in the glovebox was kept constant at 20 ± 0.5 °C. The temperature of the samples was determined using a Pt100 resistor.

4.3 *Ex situ* characterization

X-ray diffraction measurements were performed with a Panalytical X'PERT-PRO diffractometer using Cu K_α-radiation. The samples were measured for 53 min between 2θ = 10° and 70° in Bragg-Brentano geometry. All measured patterns were corrected for Cu K_α-emission using the X'Pert Highscore Plus software tool.

X-ray fluorescence was measured in a custom system (IFG) using a rhodium tube with a micro-focus capillary optics with a focus spot size of 100 μm. The fluorescence signal is detected with an energy dispersive detector with a resolution of 190 eV. For the measurements of the Cl-content a mean value and the standard deviation was calculated from 4 spots of each sample. The standard deviation of the Cl content lies between 0.1 and 0.2% and thus is smaller than the marker size in Fig. 4d.

Time-resolved photoluminescence was measured by excitation with a pulsed laser with 660 nm wavelength (pulse duration 100 ps) detection with a Si-Avalanche Photo Diode (time resolution 60 ps). Repetition rates of either 1 MHz or 250 kHz were used, depending on the transients measured. The excitation density, calculated from the time-averaged laser power, the repetition rate of the pulses, the spot size of the laser on the sample and absorption coefficient was $\Phi = 2.45 \times 10^{15}$ photons per cm³ per pulse.

Conflicts of interest

There are no conflicts to declare.

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